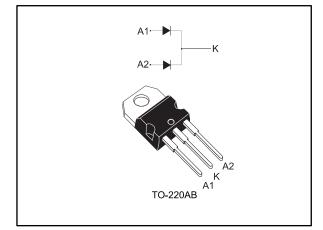


STPS60170C

High voltage power Schottky rectifier

Datasheet - production data



Description

This dual diode Schottky rectifier is suited for high frequency switched mode power supplies.

Packaged in TO-220AB this device is intended for use to enhance the reliability of the application.

Table 1: Device summary

Value
2 x 30 A
170 V
175 °C
0.76 V

Features

- High junction temperature capability
- Good trade-off between leakage current and forward voltage drop

This is information on a product in full production.

- Low leakage current
- Low thermal resistance
- Avalanche capability specified
- High frequency operation
- ECOPACK[®]2 compliant component

1 Characteristics

Table 2: Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Paramete	Value	Unit		
Vrrm	Repetitive peak reverse voltage			170	V
I _{F(RMS)}	Forward rms current			45	А
1	Average forward current δ = 0.5,	ward current δ = 0.5, T _c = 150 °C		30	А
I _{F(AV)}	square wave	$1_{\rm C} = 150^{-1}{\rm C}$	Per device	60	A
IFSM	Surge non repetitive forward currenttp = 10 ms sinusoidal			270	А
Parm	$ \begin{array}{l} \mbox{Repetitive peak avalanche power} & t_p = 10 \ \mbox{\mu s}, \\ T_j = 125 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \$			985	W
T _{stg}	Storage temperature range			-65 to +175	℃.
Tj	Maximum operating junction temperature ⁽¹⁾			175	C

Notes:

 $^{(1)}(dP_{tot}/dT_j) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 3: Thermal parameters

Symbol	Parameter Max. value			Unit
Durin	lunction to page	Per diode	Per diode 1.0	
R _{th(j-c)}	Junction to case	Total	0.7	°C/W
Rth(c)	Coupling		0.4	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_{j \text{ (diode1)}} = P_{(\text{diode1})} x R_{\text{th}(j-c)} \text{ (per diode)} + P_{(\text{diode2})} x R_{\text{th}(c)}$

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
IR ⁽¹⁾	Reverse leakage current	Tj = 25 °C	Vr = Vrrm	-		35	μA
		Tj = 125 °C		-	8	35	mA
	$V_{F}^{(2)} Forward voltage drop \qquad \qquad \frac{T_{j} = 25 \text{ °C}}{T_{j} = 125 \text{ °C}} I_{F} = 30 \text{ A}$ $T_{j} = 25 \text{ °C} I_{F} = 30 \text{ A}$	-		0.94			
V _F ⁽²⁾		Tj = 125 °C	IF = 30 A	-	0.72	0.76	V
		Tj = 25 °C		-	0.97	1.05	v
		T _j = 125 °C	I _F = 60 A	-	0.86	0.92	

Notes:

 $^{(1)} \mathsf{Pulse}$ test: t_p = 5 ms, δ < 2% $^{(2)} \mathsf{Pulse}$ test: t_p = 380 µs, δ < 2%

To evaluate the conduction losses, use the following equation:

 $P = 0.60 \text{ x } I_{F(AV)} + 0.0053 \text{ x } I_{F^2(RMS)}$

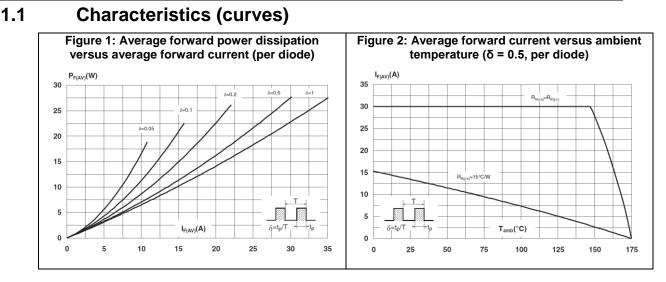
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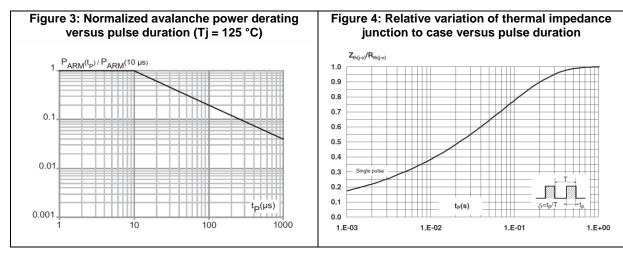


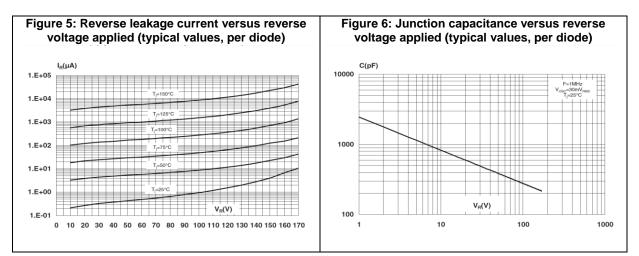
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Characteristics



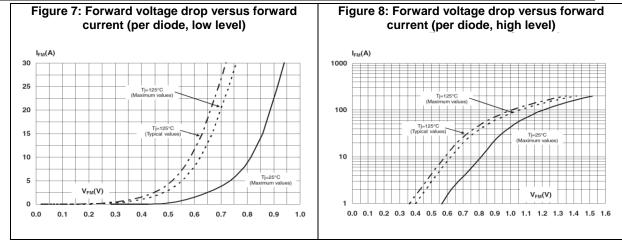




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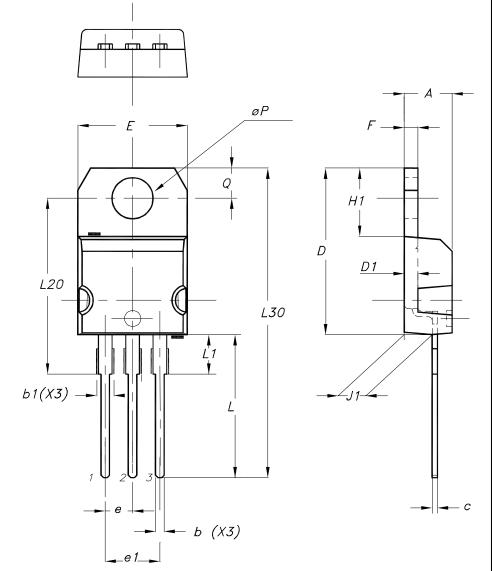
2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0
- Recommended torque value: 0.55 N·m
- Maximum torque value: 0.7 N·m

2.1 TO-220AB package information







Package information

STPS60170C

Table 5: TO-220AB package mechanical data						
Dimensions						
Ref.	Millimeters		Incl	hes		
	Min.	Max.	Min.	Max.		
А	4.40	4.60	0.173	0.181		
b	0.61	0.88	0.240	0.035		
b1	1.14	1.70	0.045	0.067		
с	0.48	0.70	0.019	0.028		
D	15.25	15.75	0.600	0.620		
D1	1.27 typ.		0.050 typ.			
E	10.00 10.		0.394	0.409		
е	2.40	2.70	0.094	0.106		
e1	4.95	5.15	0.195	0.203		
F	1.23	1.32	0.048	0.052		
H1	6.20	6.60	0.244	0.260		
J1	2.40	2.72	0.094	0.107		
L	13.00	14.00	0.512	0.551		
L1	3.50	3.93	0.138	0.155		
L20	16.40 typ.		0.646	δ typ.		
L30	28.90 typ.		1.138	3 typ.		
θΡ	3.75	3.85	0.148	0.152		
Q	2.65	2.95	0.104	0.116		

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3 Ordering information

Table 6: Ordering information						
Order code Marking Package Weight Base qty. Delivery mod				Delivery mode		
STPS60170CT	STPS60170CT	TO-220AB	1.95 g	50	Tube	

4 Revision history

Table 7: Document r	revision history	
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Date	Revision	Changes
18-Feb-2005	1	First issue.
11-Dec-2015	2	Updated conduction losses equation values and reformatted to current standard.
15-Jan-2018	3	Updated Table 2: "Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)".



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